| Examiner-Initiated Interview Summary | | Application No. | Applicant(s) |
|---|---|-----------------------------------|---------------------------------|
| | | 10/538,529 | MACCALLI ET AL. |
| | | Examiner | Art Unit |
| | | Sylvia R. MacArthur | 1792 |
| All Participants: | | Status of Application: | _ |
| (1) Sylvia R. MacArt | <u>hur</u> . | (3) | |
| (2) John Parzych. | | (4) | |
| Date of Interview: 30 | July 2009 | Time: | |
| Type of Interview: ☑ Telephonic ☐ Video Conference ☐ Personal (Copy given to: ☐ Applicant Exhibit Shown or Demonstrated: ☐ Yes If Yes, provide a brief description: | | | |
| Part I. | | | |
| Rejection(s) discussed: | | | |
| Claims discussed: 20 and 21 Prior art documents discussed: | | | |
| Part II. | | | |
| SUBSTANCE OF INTERVIEW DESCRIBING THE GENERAL NATURE OF WHAT WAS DISCUSSED: See Continuation Sheet | | | |
| Part III. | | | |
| It is not necessary for applicant to provide a separate record of the substance of the interview, since the interview directly resulted in the allowance of the application. The examiner will provide a written summary of the substance of the interview in the Notice of Allowability. It is not necessary for applicant to provide a separate record of the substance of the interview, since the interview did not result in resolution of all issues. A brief summary by the examiner appears in Part II above. | | | |
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| July 30, 2009 | /Sylvia R MacArthur/ Primary Examiner, Art Unit 1792 | Applicant/Applicant's Representat | ive Signature – if appropriate) |

Continuation of Substance of Interview including description of the general nature of what was discussed: The examiner contacted Mr. Parzych to inform him that claims 20 and 21 were amended to correct the dependency statements. Specifically, claims 20 and 21 will read as follows:

 (Currently amended) Apparatus according to any one of claims 15 to 19, comprising means for causing at least one gas-flow to flow in at least one through-hole (21, 31) of the susceptor system.

21. (Currently amended) Apparatus according to claim 15 characterized in that it is a reactor for the epitaxial growth of silicon carbide or similar material on substrates.

A marked up copy of the claims will be further provided for applicant's convenience.